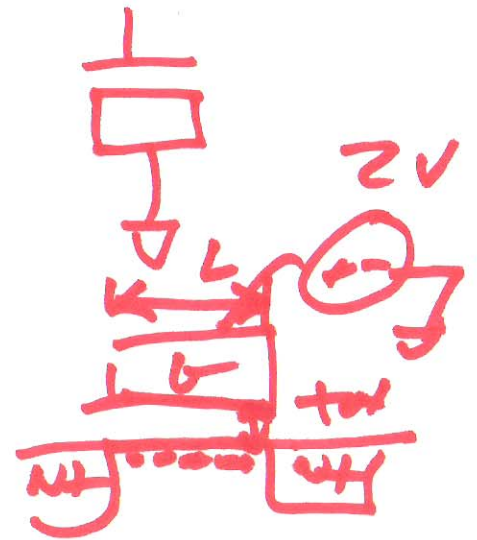
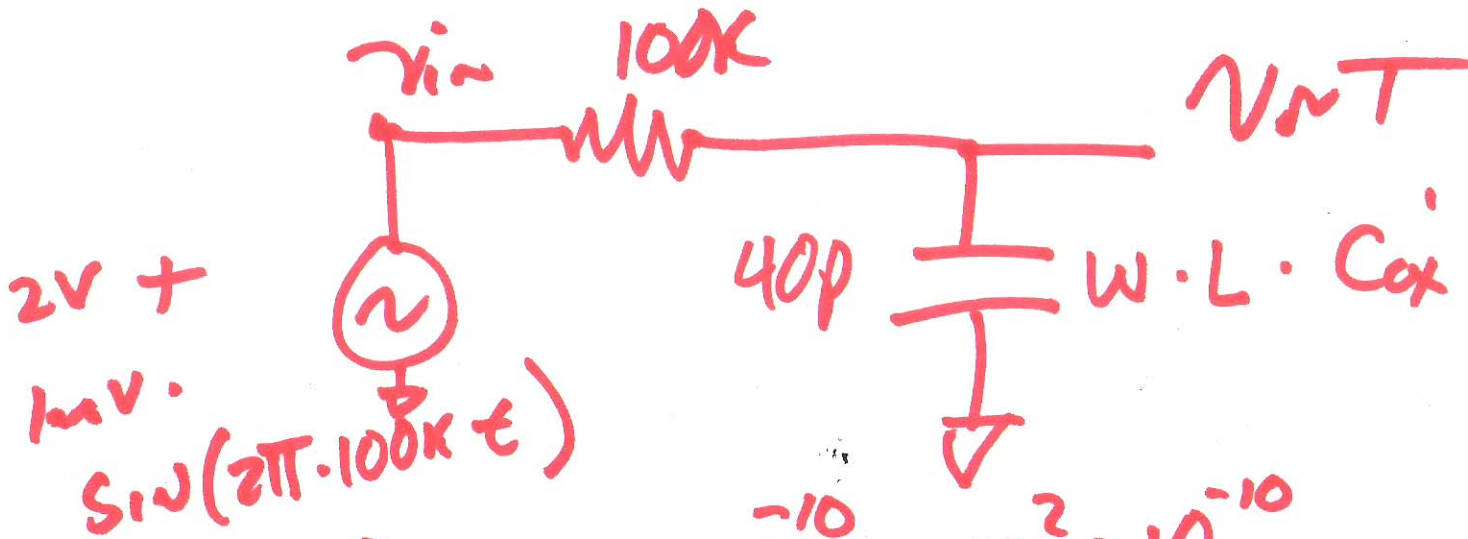


# EE 320 Electronics

3/31/14



$$100 \text{ \AA} = 100 \cdot 10^{-10} = 10^2 \cdot 10^{-10}$$

$$0.01 \mu = 10 \text{ nm} = 10^{-8}$$

P-Si

$$C_{ox} = \frac{3.9 \cdot 8.85 \times 10^{-12} \text{ F/m}}{t_{ox}}$$

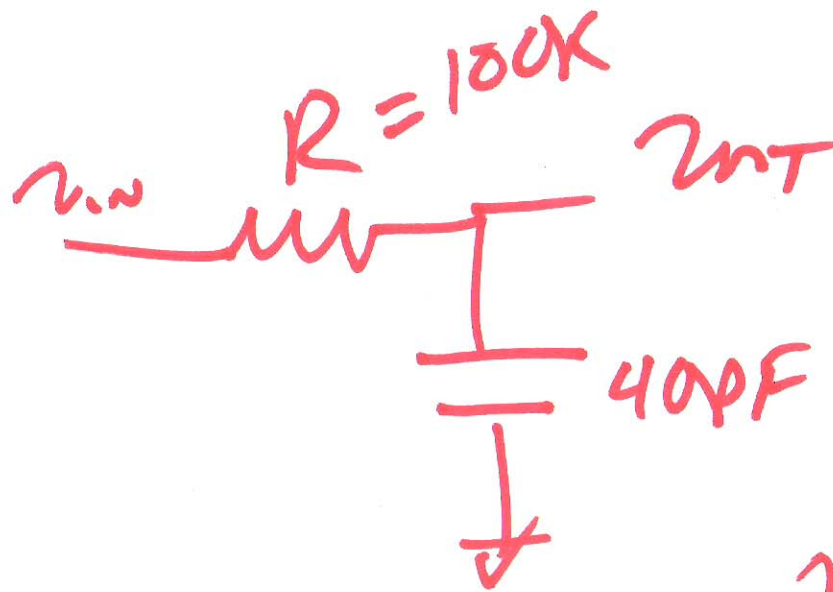
$$C_{ox} \approx 2$$

$$C = W \cdot L \cdot C_{ox}$$

$$= 100 \mu \cdot 100 \mu \cdot \frac{3.9 \cdot 8.85 \times 10^{-12} \text{ F}}{0.01 \mu}$$

$$\approx 40 \text{ pF}$$

17



$$v_{out} = \frac{v_{in} \cdot \frac{1}{j\omega 40p}}{\frac{1}{j\omega 40p} + 100k}$$

$$v_{out} = v_{in} \cdot \frac{1}{1 + j \cdot 2\pi \cdot 100k \cdot 40pF}$$

~~$10^{10} \cdot 40 \cdot 10^{-12}$~~   
 $\cdot 4$

$6.28 \cdot 4 \approx 2.5$

$\tan^{-1} 2.5 = \approx 68^\circ$

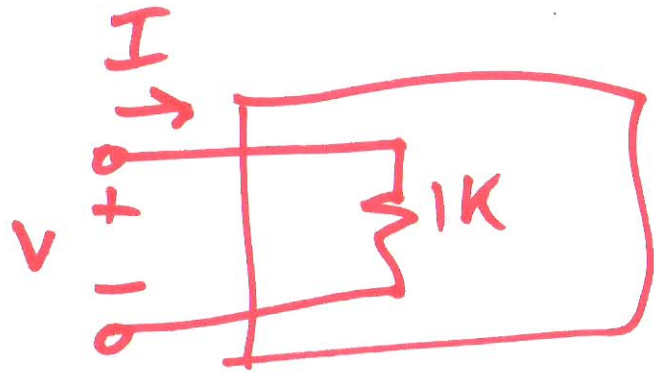
$\theta = \frac{t_d}{T} \cdot 360$

$t_d \approx 1.64s$

$|v_{out}| = 1\mu V \cdot \frac{1}{\sqrt{1^2 + (2.5)^2}}$

$|v_{out}| \approx 4\mu V$

2)

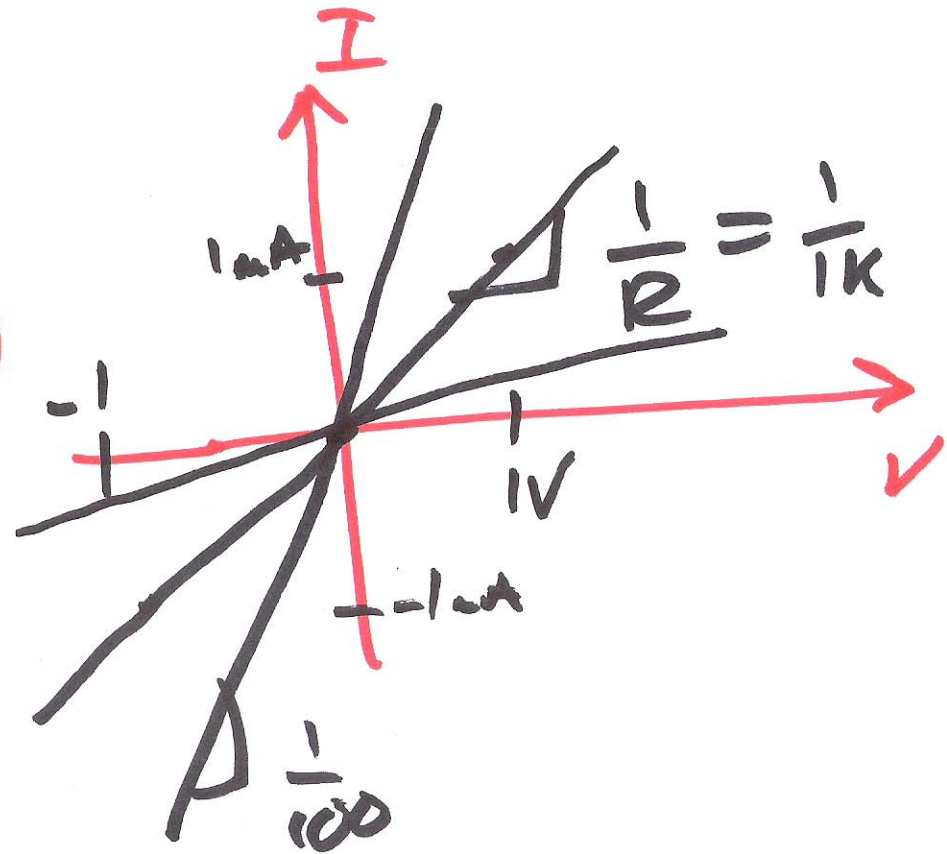


$$V = I \cdot 1K$$

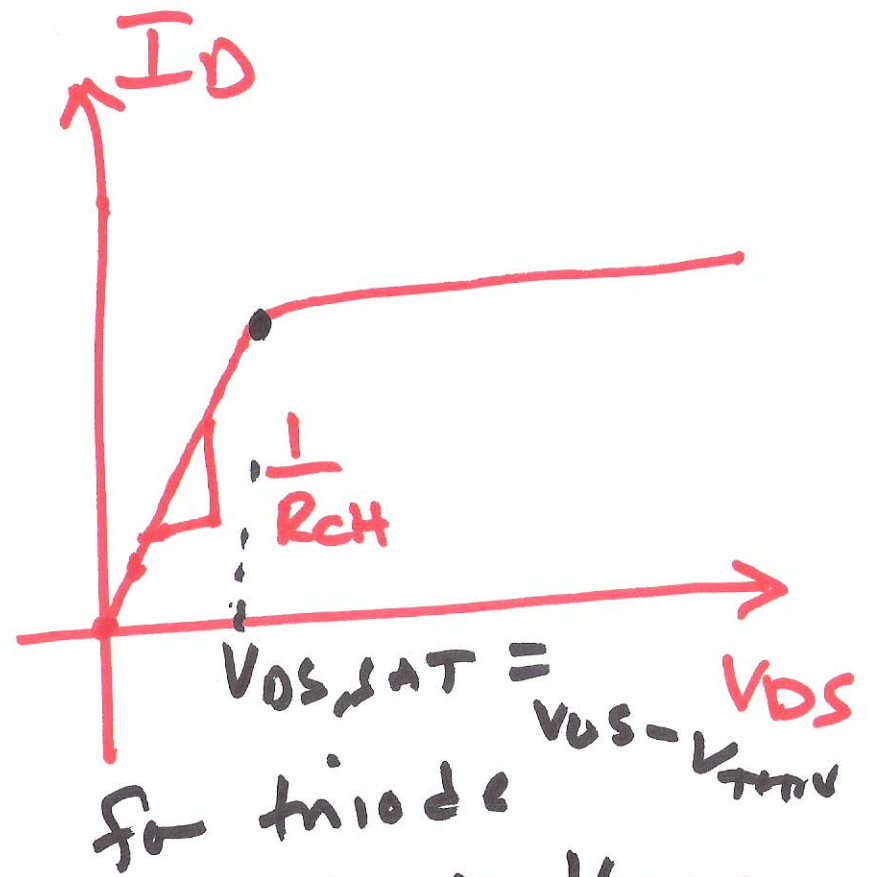
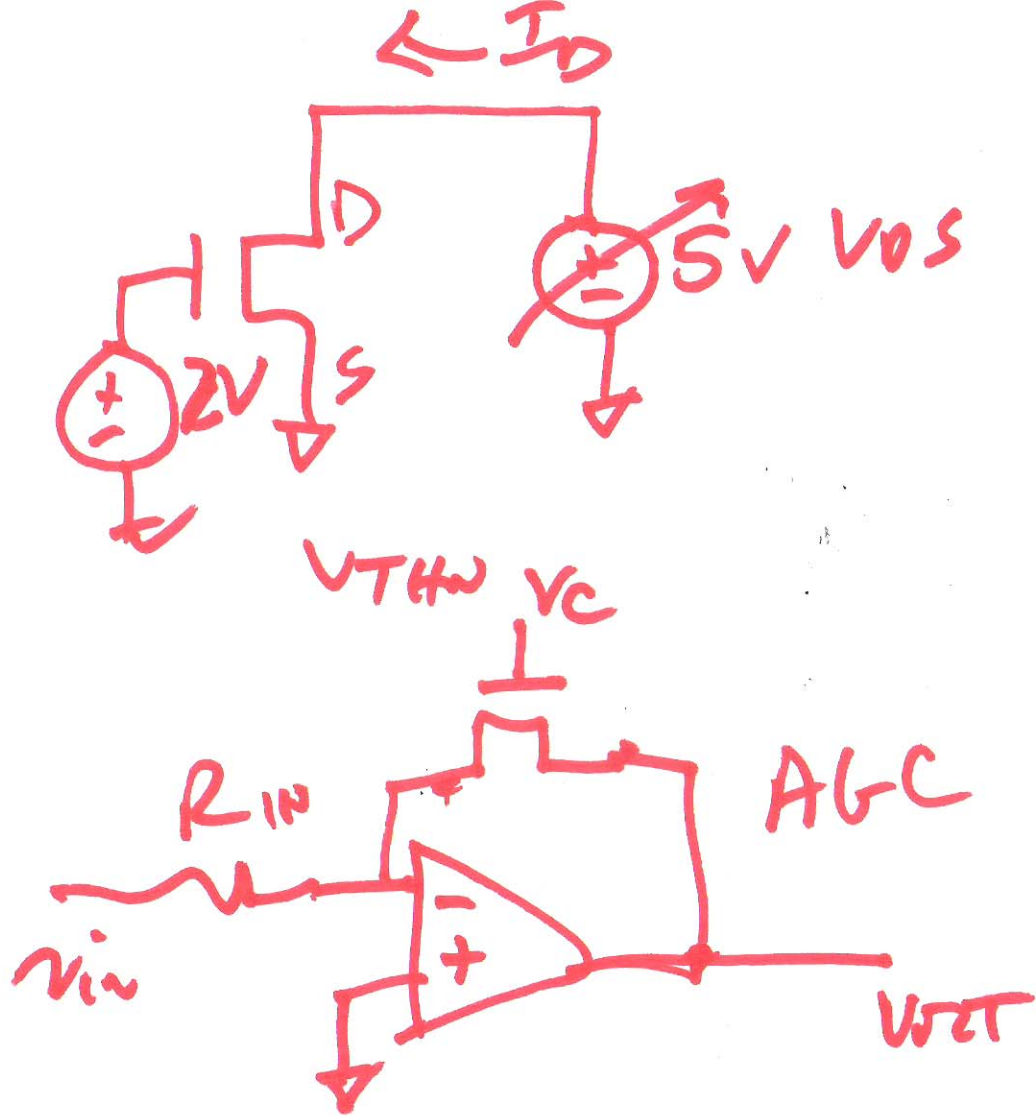
$$I = \frac{V}{1K}$$

$$R = 100$$

$$R = 10^3$$



3)



for triode

$$V_{GS} > V_{THN}$$

$$V_{DS} \leq V_{GS} - V_{THN}$$

$$\frac{V_{OUT}}{V_{IN}} = -\frac{R_{CH}}{R_{IN}}$$

$$I_D = K_P \cdot \frac{W}{L} \left( (V_{GS} - V_{THN}) \cdot V_{DS} - \frac{V_{DS}^2}{2} \right)$$

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$$I_D = K_P \frac{W}{L} \left( (V_{GS} - V_{THN}) V_{DS} - \frac{V_{DS}^2}{2} \right)$$

triode →

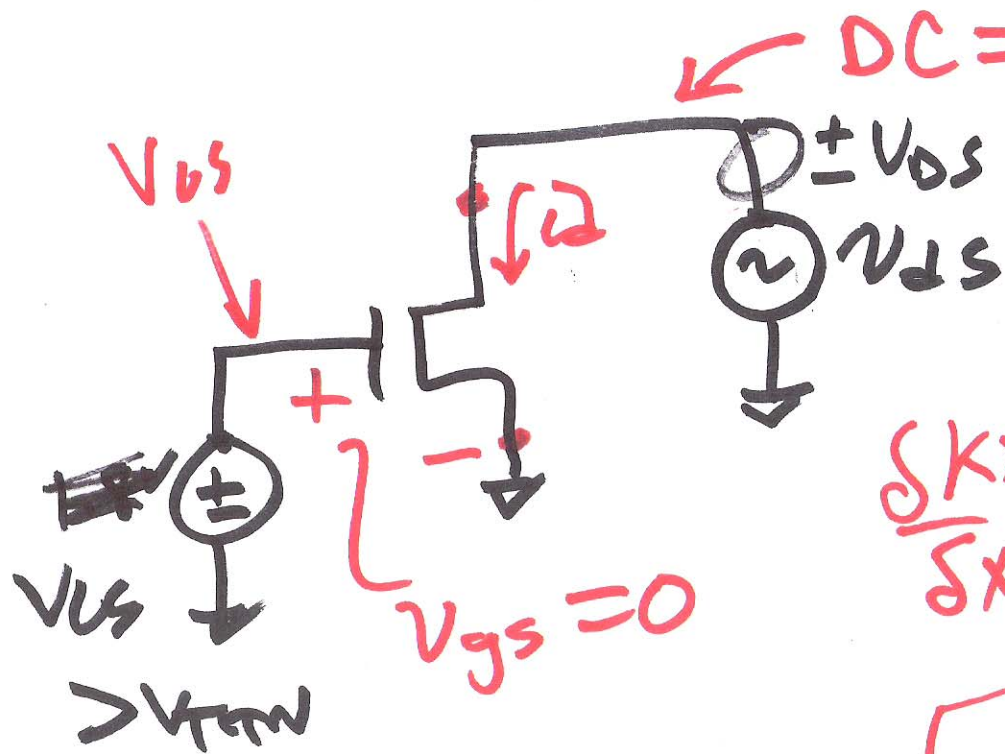
for SAT

$$V_{DS} = V_{GS} - V_{THN}$$

$$I_D = K_P \frac{W}{L} \left( (V_{GS} - V_{THN})^2 - \frac{(V_{GS} - V_{THN})^2}{2} \right)$$

$$= \frac{K_P W}{2L} (V_{GS} - V_{THN})^2$$

SATURATION!



$V_{DS} \geq V_{GS} - V_{THN}$  for SAT

$\frac{\delta K X^2}{\delta X} = 2KX \cdot \frac{\delta X}{\delta X} \geq \text{pos. \#}$

NO!

$\frac{1}{R_{eff}} = \frac{\delta I_D}{\delta V_{DS}} = \frac{\delta}{\delta V_{DS}} \left[ \frac{K_P \cdot W}{L} \left( (V_{GS} - V_{THN}) V_{DS} - \frac{V_{DS}^2}{2} \right) \right]$  (in triode)

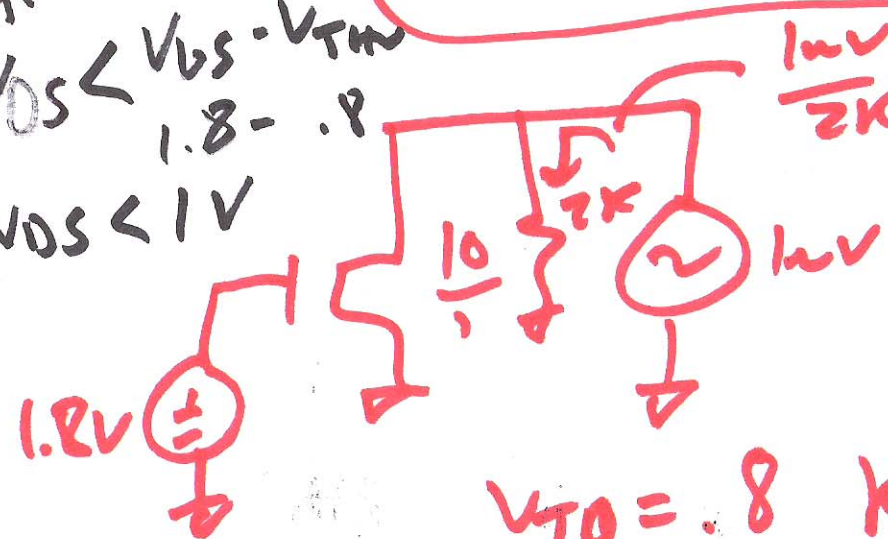
$I_D = \text{CONST}$   
 $V_{DS} = \text{CONST} = K_P \frac{W}{L} \left[ \frac{1}{2} (V_{GS} - V_{THN})^2 - V_{DS} \right]$

6)

$$\frac{1}{R_{ch}} = K_P \frac{W}{L} \left[ (V_{GS} - V_{TH}) - V_{DS} \right]$$

$$R_{ch} \approx \frac{1}{K_P \cdot \frac{W}{L} (V_{GS} - V_{TH})}$$

for triode  
 $V_{DS} < V_{GS} - V_{TH}$   
 $1.8 - .8$   
 $V_{DS} < 1V$



$$\frac{1\mu V}{2K} = \frac{1}{2} \mu A$$

$$R_{ch} =$$

$$\frac{1}{50\mu A \cdot \frac{10}{1} (1)}$$

$$= \frac{1}{500\mu A} = \underline{\underline{2K}}$$

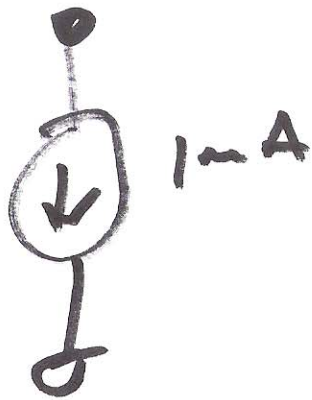
$$V_{TH} = .8 \quad K_P = 50\mu A$$

7)

$$I_D = \frac{K_P W}{2 L} (V_{GS} - V_{THN})^2$$

$$V_{GS} = \sqrt{\frac{2 I_D}{K_P \cdot W/L}} + V_{THN}$$

1,000  $\mu$ A



$$= \sqrt{\frac{2000}{50 \cdot 100}} + .8$$

$$\sqrt{.4} + .8$$

$$.63 + .8$$

$$\underline{\underline{1.43V}}$$



for SHT ( $V_{GS} > V_{THN}$ )

$$V_{DS} \geq V_{GS} - V_{THN}$$

$$V_D - V_S \geq V_G - V_S - V_{THN}$$

$$V_D \geq V_G - V_{THN}$$

3.43 - .8

$$V_D \geq \underline{\underline{2.63V}}$$

a)